RoHS Compliant

Serial ATA Flash Drive

SS210-300 Product Specifications

January 17, 2017

Version 1.0

Features:

- **Compliance with SATA Revision 3.1**
  - SATA 6.0 Gbps interface
  - Backward compatible with SATA 1.5 and 3.0 Gbps interfaces
  - ATA-8 command set

- **Capacity**
  - 8, 16, 32, 64, 128 GB

- **Performance***
  - Burst read/write: 600 MB/sec
  - Sustained read: up to 530 MB/sec
  - Sustained write: up to 450 MB/sec
  - Random read 4K: up to 82,000 IOPS
  - Random write 4K: up to 77,000 IOPS

- **Flash Management**
  - Built-in hardware ECC
  - Global Wear Leveling
  - Flash bad-block management
  - Flash Translation Layer: Page Mapping
  - S.M.A.R.T.
  - Power Failure Management
  - ATA Secure Erase
  - TRIM

- **NAND Flash Type:** SLC

- **MTBF:** >2,000,000 hours

- **Temperature Range**
  - Operating:
    Standard: 0°C to 70°C
    Extended: -40°C to 85°C
  - Storage: -40°C to 100°C

- **Supply Voltage**
  - 3.3 V ± 5%

- **Power Consumption***
  - Active mode: 890 mA
  - Idle mode: 195 mA

- **Form Factor**
  - JEDEC MO-300
  - Dimensions (50.80 x 29.85 x 3.8, unit: ㎜)

- **Shock & Vibration****
  - Shock: 1,500 G
  - Vibration: 15 G

- **DRAM Cache for Enhanced Random Performance**

- **SATA Power Management Modes**

- **Device Sleep Mode**

- **Thermal Sensor**

- **LED Indicators for Drive Behavior**

- **Write Protect Switch (optional)**

- **RoHS Compliant**

*Varies from capacities. The values addressed here are typical and may vary depending on settings and platforms.
**Non-operating

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1. Product Description

1.1 Introduction

Apacer SS210-300 is a well-balanced solid-state disk (SSD) drive with compact form factor (JEDEC MO-300) and great performance. Designed in SATA 6.0 Gbps interface, the mSATA SSD is able to deliver exceptional read/write speed, making it the ideal companion for heavy-loading embedded or server operations with space constraints for host computing systems. For data efficiency, the internal controlling unit of the mSATA SSD is engineered with DRAM for enhanced random performance. In regard of reliability, the drive comes with various implementations including powerful hardware ECC engine, power saving modes, wear leveling, flash block management, S.M.A.R.T., TRIM, and power failure management.

1.2 Capacity Specifications

Table 1-1 Capacity Specifications

Capacity	Total Bytes	Cylinders	Heads	Sectors	Max LBA
8 GB	8,012,390,400	15525	16	63	15,649,200
16 GB	16,013,942,784	16,383	16	63	31,277,232
32 GB	32,017,047,552	16,383	16	63	62,533,296
64 GB	64,023,257,088	16,383	16	63	125,045,424
128 GB	128,035,676,160	16,383	16	63	250,069,680

1. Display of total bytes varies from file systems.
2. Cylinders, heads or sectors are not applicable for these capacities. Only LBA addressing applies.
3. LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the SSD is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.

1.3 Performance

Table 1-2 Performance

Performance \ Capacity	8 GB	16 GB	32 GB	64 GB	128 GB
Sustained Read (MB/s)	55	55	530	530	530
Sustained Write (MB/s)	37	45	270	440	450
Random Read IOPS (4K)	12,000	10,000	81,000	82,000	82,000
Random Write IOPS (4K)	4,000	9,000	62,000	76,000	77,000

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1.4 Pin Assignments

Pin assignment of the SS210-300 is shown in Figure 1-1 and described in Table 1-3.

Pin 1   Pin 51

Figure 1-1 Pin Assignment

Table 1-3 Pin Assignment Description

Pin	Type	Description	Pin	Type	Description
1	Reserved	No Connect	27	GND	Ground
2	+3.3V	3.3V source	28	Reserved	No Connect
3	Reserved	No Connect	29	GND	Ground
4	GND	Ground	30	Reserved	No Connect
5	Reserved	No Connect	31	-A	Host Transmitter Differential Signal Pair
6	Reserved	No Connect	32	Reserved	No Connect
7	Reserved	No Connect	33	+A	Host Transmitter Differential Signal Pair
8	Reserved	No Connect	34	GND	Ground
9	GND	Ground	35	GND	Ground
10	Reserved	No Connect	36	Reserved	No Connect
11	Reserved	No Connect	37	GND	Ground
12	Reserved	No Connect	38	Reserved	No Connect
13	Reserved	No Connect	39	+3.3V	3.3V source
14	Reserved	No Connect	40	GND	Ground
15	GND	Ground	41	+3.3V	3.3V source
16	Reserved	No Connect	42	Reserved	No Connect
17	Reserved	No Connect	43	Device Type	No Connect
18	GND	Ground	44	DEVSLP	Device Sleep
19	Reserved	No Connect	45	Reserved	No Connect
20	Reserved	No Connect	46	Reserved	No Connect
21	GND	Ground	47	Reserved	No Connect
22	Reserved	No Connect	48	Reserved	No Connect
23	+B	Host Receiver Differential Signal Pair	49	DAS/DSS	Device Activity Signal/Disable Staggered Spin-up
24	+3.3V	3.3V Source	50	GND	Ground
25	-B	Host Receiver Differential Signal Pair	51*	Detect	0 ohm
26	GND	Ground	52	+3.3V	3.3V source

*Notes about Pin51: It is a presence detection pin that shall be connected to GND by a 0 ohm to 220 ohm Resistor on device. Please see the diagram below.

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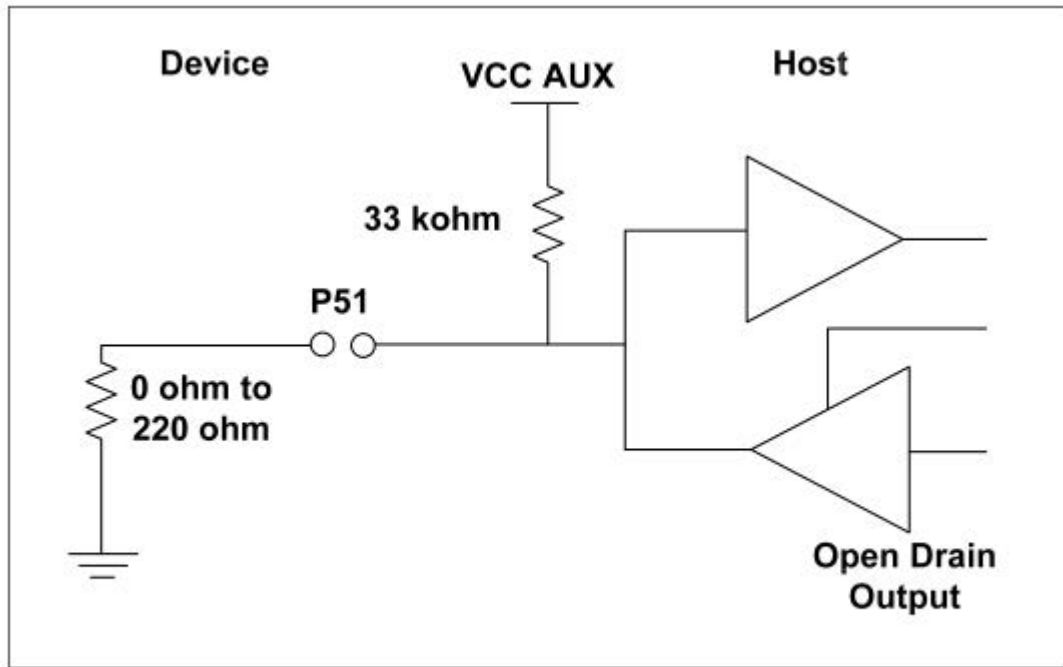
Bi-directional host-side implementation of P51 for compatibility with non-mSATA devices (informative)

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1.5 LED Indicator Behavior

The behavior of the SS210-300 LED indicators is described in Table 1-4.

Table 1-4 LED Behavior

Location	Status	Description
LED A	Blinking	Accessing drive
	Static	Write Protect is enabled (only available for models supporting write protection)
LED B	Static	PHY is connected

8-16GB

32-128GB

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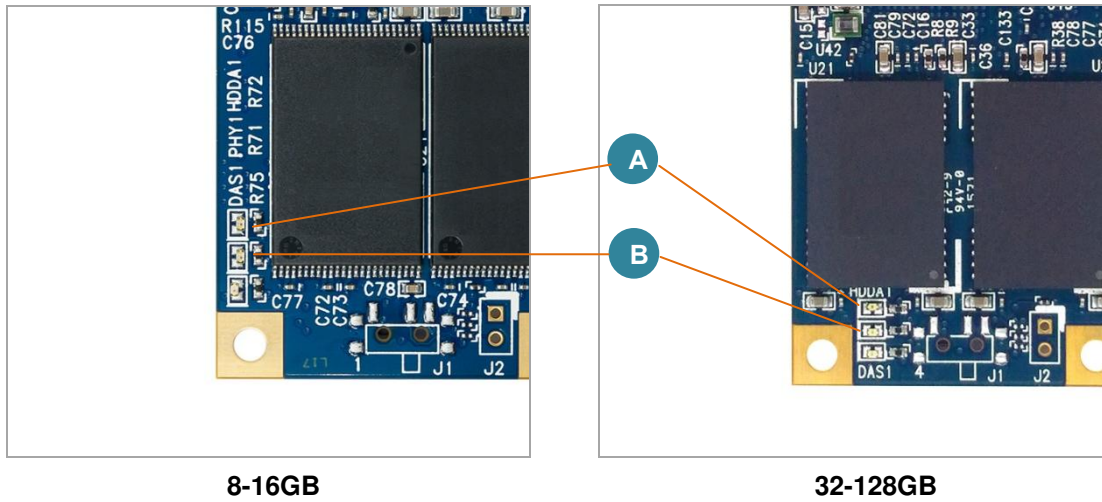
2. Software Interface

2.1 Command Set

Table 2-1 summarizes the ATA commands supported by SS210-300.

Table 2-1 Command Set

Code	Command	Code	Command
E5h	Check Power Mode	F6h	Security Disable Password
90h	Execute Diagnostics	F3h	Security Erase Prepare
E7h	Flush Cache	F4h	Security Erase Unit
ECh	Identify Device	F5h	Security Freeze Lock
E3h	Idle	F1h	Security Set Password
E1h	Idle Immediate	F2h	Security Unlock
91h	Initialize Device Parameters	7Xh	Seek
C8h	Read DMA	EFh	Set Features
25h	Read DMA EXT	C6h	Set Multiple Mode
60h	Read FPDMA Queued	E6h	Sleep
47h	Read Log DMA EXT	B0h	S.M.A.R.T.
2Fh	Read Log EXT	E2h	Standby
C4h	Read Multiple	E0h	Standby Immediate
20 or 21h	Read Sector(s)	CAh	Write DMA
40 or 41h	Read Verify Sector(s)	35h	Write DMA EXT
10h	Recalibrate	61h	Write FPDMA Queued
57h	Write Log DMA EXT	3Fh	Write Log EXT
C5h	Write Multiple	30h or 31h	Write Sector(s)

2.2 S.M.A.R.T.

S.M.A.R.T. is an abbreviation for Self-Monitoring, Analysis and Reporting Technology, a self-monitoring system that provides indicators of drive health as well as potential disk problems. It serves as a warning for users from unscheduled downtime by monitoring and displaying critical drive information. Ideally, this should allow taking proactive actions to prevent drive failure and make use of S.M.A.R.T. information for future product development reference.

Apacer devices use the standard SMART command B0h to read data out from the drive to activate our S.M.A.R.T. feature that complies with the ATA/ATAPI specifications. S.M.A.R.T. Attribute IDs shall include initial bad block count, total later bad block count, maximum erase count, average erase count, power on hours and power cycle. When the S.M.A.R.T. Utility running on the host, it analyzes and reports the disk status to the host before the device reaches in critical condition.

Note: Attribute IDs may vary from product models due to various solution design and supporting capabilities.

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Apacer memory products come with S.M.A.R.T. commands and subcommands for users to obtain information of drive status and to predict potential drive failures. Users can take advantage of the following commands/subcommands to monitor the health of the drive.

Code	SMART Subcommand
D0h	READ DATA
D1h	READ ATTRIBUTE THRESHOLDS
D2h	Enable/Disable Attribute Autosave
D4h	Execute Off-line Immediate
D5h	Read Log (optional)
D6h	Write Log (optional)
D8h	Enable Operations
D9h	Disable operations
DAh	Return Status

General SMART attribute structure

Byte	Description
0	ID (Hex)
1 – 2	Status flag
3	Value
4	Worst
5*-11	Raw Data

*Byte 5: LSB

SMART attribute ID list

ID (Hex)	Attribute Name
9 (0x09)	Power-on hours
12 (0x0C)	Power cycle count
163 (0xA3)	Max. erase count
164 (0xA4)	Avg. erase count
166 (0xA6)	Total later bad block count
167 (0xA7)	SSD Protect Mode (vendor specific)
168 (0xA8)	SATA PHY Error Count
175 (0xAF)	Bad Cluster Table Count
192 (0xC0)	Unexpected Power Loss Count
194 (0xC2)	Temperature
241 (0xF1)	Total sectors of write

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3. Flash Management

3.1 Error Correction/Detection

SS210-300 implements a hardware ECC scheme, based on the BCH algorithm. It can detect and correct up to 40 bits error in 1K bytes.

3.2 Bad Block Management

Current production technology is unable to guarantee total reliability of NAND flash memory array. When a flash memory device leaves factory, it comes with a minimal number of initial bad blocks during production or out-of-factory as there is no currently known technology that produce flash chips free of bad blocks. In addition, bad blocks may develop during program/erase cycles. When host performs program/erase command on a block, bad block may appear in Status Register. Since bad blocks are inevitable, the solution is to keep them in control. Apacer flash devices are programmed with ECC, block mapping technique and S.M.A.R.T to reduce invalidity or error. Once bad blocks are detected, data in those blocks will be transferred to free blocks and error will be corrected by designated algorithms.

3.3 Global Wear Leveling

Flash memory devices differ from Hard Disk Drives (HDDs) in terms of how blocks are utilized. For HDDs, when a change is made to stored data, like erase or update, the controller mechanism on HDDs will perform overwrites on blocks. Unlike HDDs, flash blocks cannot be overwritten and each P/E cycle wears down the lifespan of blocks gradually. Repeatedly program/erase cycles performed on the same memory cells will eventually cause some blocks to age faster than others. This would bring flash storages to their end of service term sooner. Global wear leveling is an important mechanism that levels out the wearing of all blocks so that the wearing-down of all blocks can be almost evenly distributed. This will increase the lifespan of SSDs.

3.4 Power Failure Management

Power Failure Management plays a crucial role when experiencing unstable power supply. Power disruption may occur when users are storing data into the SSD. In this urgent situation, the controller would run multiple write-to-flash cycles to store the metadata for later block rebuilding. This urgent operation requires about several milliseconds to get it done. At the next power up, the firmware will perform a status tracking to retrieve the mapping table and resume previously programmed NAND blocks to check if there is any incompleteness of transmission.

Note: The controller unit of this product model is designed with a DRAM as a write cache for improved performance and data efficiency. Though unlikely to happen in most cases, the data cached in the volatile DRAM might be potentially affected if a sudden power loss takes place before the cached data is flushed into non-volatile NAND flash memory.

3.5 ATA Secure Erase

ATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.

3.6 TRIM

TRIM is a SATA command that helps improve the read/write performance and efficiency of solid-state drives (SSD). The command enables the host operating system to inform SSD controller which blocks contain invalid data, mostly because of the erase commands from host. The invalid will be discarded permanently and the SSD will retain more space for itself.

3.7 Flash Translation Layer – Page Mapping

Page mapping is a 4K-based firmware technology whose essence lies in the ability to gather data, distribute the data into 4KB blocks automatically, and then schedule the data to be evenly written. This implementation is also evidenced by JEDEC that 4KB is the most frequently used block size for data read/write access, constituting 67% of server workload. Thus, 4K page mapping is adopted to increase random access speed and improve SSD lifespan, reduce block erase frequency, and achieve optimized performance and lifespan.

3.8 DEVSLP (DevSleep or DEVSLP) Mode

Device Sleep is a feature that allows SATA devices to enter a low power mode by designating pin 44 as DEVSLP signal with an aim to reducing power consumption.

3.9 Thermal Sensor

Apacer Thermal Sensor is a digital temperature sensor with serial interface. By using designated pins for transmission, storage device owners are able to read temperature data.

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3.10 SATA Power Management

By complying with SATA 6.0 Gb/s specifications, the SSD supports the following SATA power saving modes:

- ACTIVE: PHY ready, full power, Tx & Rx operational

- PARTIAL: Reduces power, resumes in under 10 µs (microseconds)

- SLUMBER: Reduces power, resumes in under 10 ms (milliseconds)

- HIPM: Host-Initiated Power Management

- DIPM: Device-Initiated Power Management

- AUTO-SLUMBER: Automatic transition from partial to slumber.

- Device Sleep (DevSleep or DEVSLP): PHY powered down; power consumption $\leq$ 5 mW; host assertion time $\leq$ 10 ms; exit timeout from this state $\leq$ 20 ms (unless specified otherwise in SATA Identify Device Log).

Note: The behaviors of power management features would depend on host/device settings.

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4. Reliability Specifications

4.1 Environmental

SS210-300 environmental specifications follow MIL-STD-810F, as indicated in the following table.

Table 4-1 Environmental Specifications

Environment	Specifications
Temperature	0℃ to 70℃ (Standard); -40°C to 85°C (Extended)
	-40°C to 100°C (Non-operating)
Vibration	Non-operating: Sine wave, 15(G), 10~2000(Hz), Operating: Random, 7.69(Grms), 20~2000(Hz)
Shock	Non-operating: Acceleration, 1,500 G, 0.5 ms Operating: Peak acceleration, 50 G, 11 ms

4.2 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in SATA drive. The prediction result for the SS210-300 is more than 2,000,000 hours.

Note: the MTBF is predicated and calculated based on "Telcordia Technologies Special Report, SR-332, Issue 2" method.

4.3 Certification and Compliance

SS210-300 complies with the following standards:

- CE
- FCC
- RoHS
- MIL-STD-810F

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5. Electrical Characteristics

5.1 Operating Voltage

Table 5-1 lists the supply voltage for SS210-300.

Table 5-1 Operating Voltage

Parameter	Conditions
Supply Voltage	3.3V ± 5%

5.2 Power Consumption

Table 5-2 lists the power consumption for SS210-300.

Table 5-2 Typical Power Consumption

Capacity / Modes	8 GB	16 GB	32 GB	64 GB	128 GB
Active (mA)	165	250	450	680	890
Idle (mA)	80	115	160	160	160

Note: Results may differ from various flash configurations or host system setting.

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6. Mechanical Specifications

6.1 Dimensions
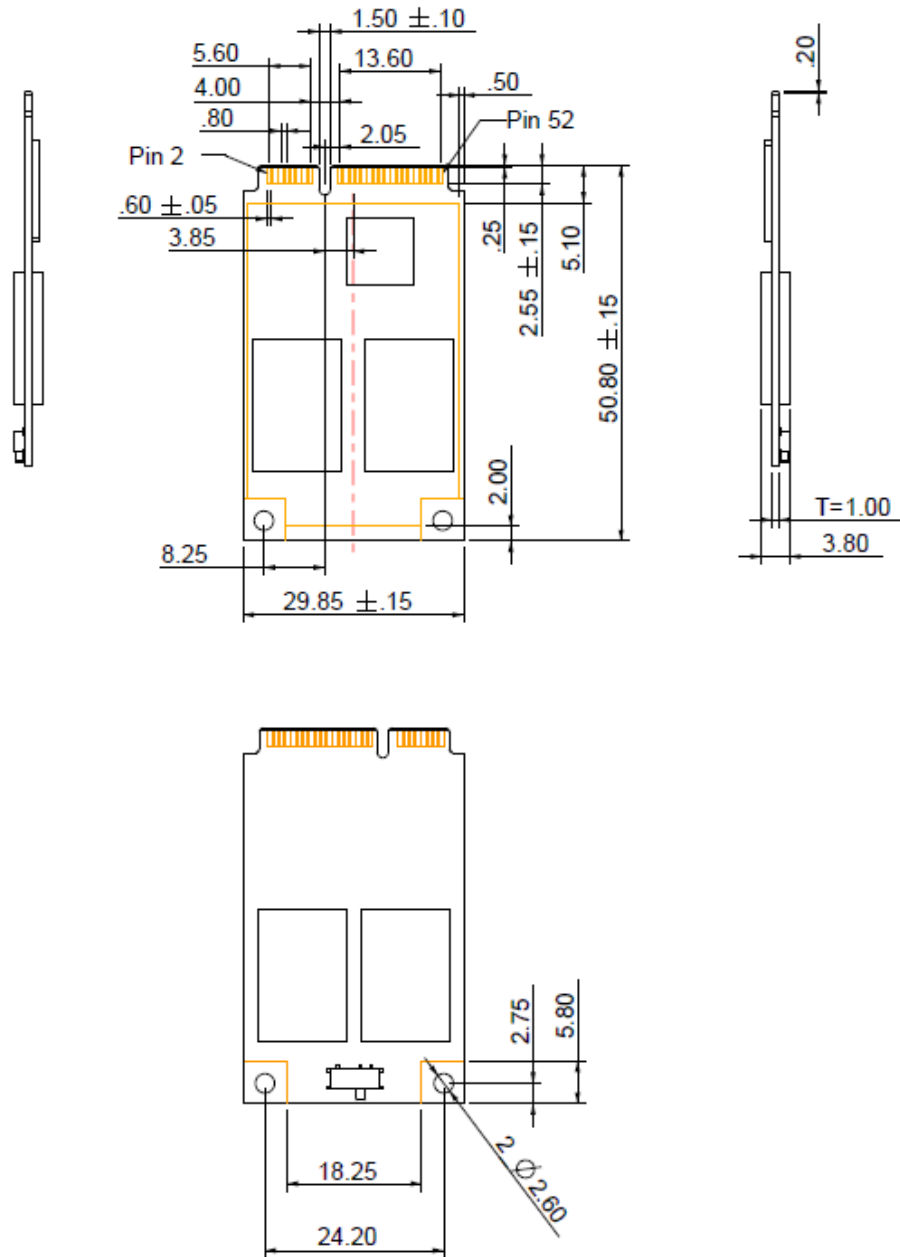
Unit: mm
Tolerance: ± 0.2

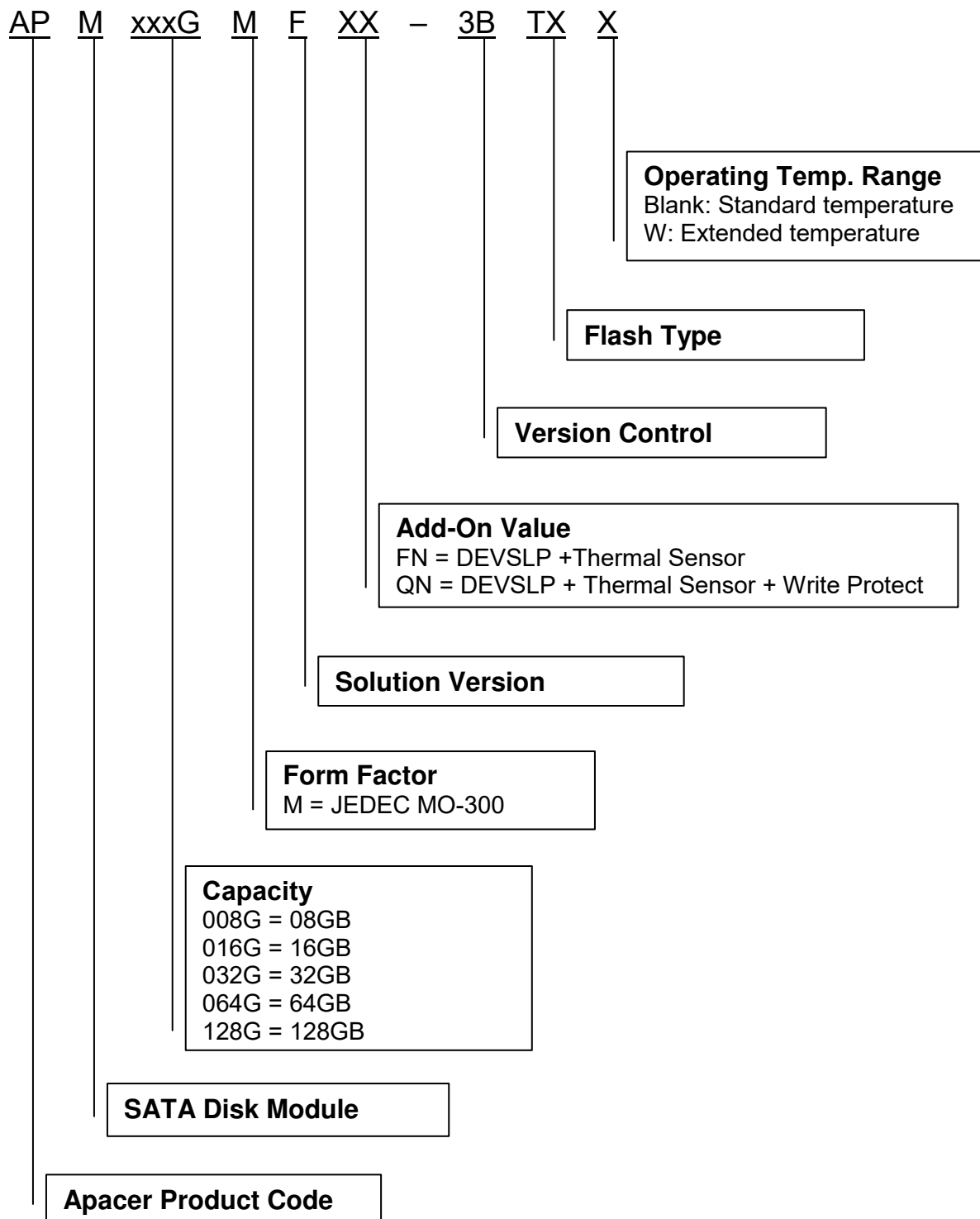Rev. 1.0

6.2 Write Protect Switch (optional)

Apacer implements the Virtual Write scheme that allows write commands to go through the flash controller and data temporarily stored, but no data has been actually written into the flash. Once the system is reset and rebooted, the temporarily stored data will be lost and nowhere to be found in the system. Since the Virtual Write scheme runs at device level, it requires no software or driver installation and is independent from the host OS.

Write Protect Switch

Disable   Enable (Read only)
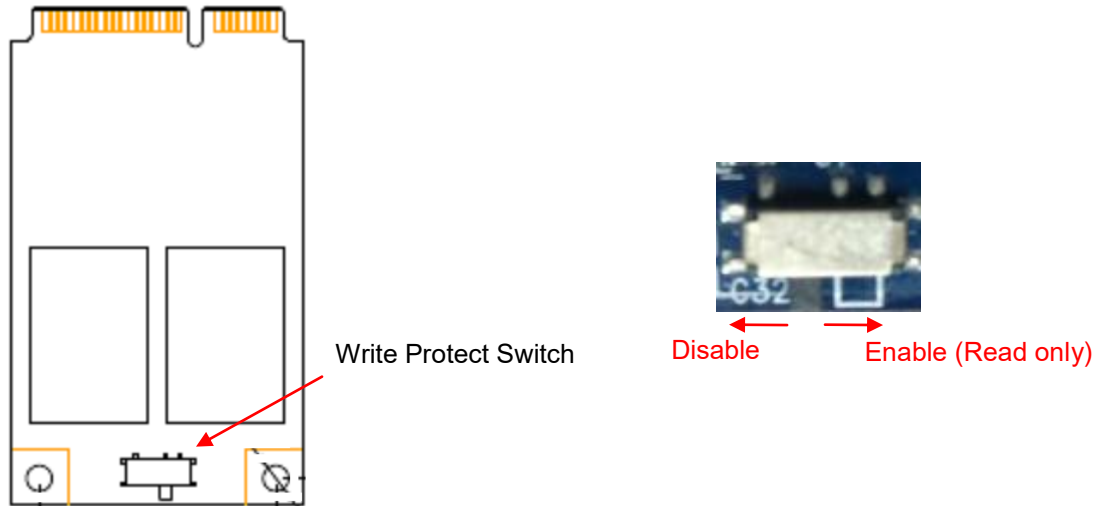
Note: Write Protect is optional and the image is for reference only.

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7. Product Ordering Information

7.1 Product Code Designations

AP M xxxG M F XX – 3B TX X

Operating Temp. Range
Blank: Standard temperature
W: Extended temperature

Flash Type

Version Control

Add-On Value
FN = DEVSLP +Thermal Sensor
QN = DEVSLP + Thermal Sensor + Write Protect

Solution Version

Form Factor
M = JEDEC MO-300

Capacity
008G = 08GB
016G = 16GB
032G = 32GB
064G = 64GB
128G = 128GB

SATA Disk Module

Apacer Product Code

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7.2 Valid Combinations

7.2.1 Standard

Capacity	Standard Temp.	Extended Temp.
8GB	APM008GMFFN-3BT	APM008GMFFN-3BTW
16GB	APM016GMFFN-3BT	APM016GMFFN-3BTW
32GB	APM032GMFFN-3BTG	APM032GMFFN-3BTGW
64GB	APM064GMFFN-3BTG	APM064GMFFN-3BTGW
128GB	APM128GMFFN-3BTG	APM128GMFFN-3BTGW

7.2.2 With Write Protect (optional)

Capacity	Standard Temp.	Extended Temp.
8GB	APM008GMFQN-3BT	APM008GMFQN-3BTW
16GB	APM016GMFQN-3BT	APM016GMFQN-3BTW
32GB	APM032GMFQN-3BTG	APM032GMFQN-3BTGW
64GB	APM064GMFQN-3BTG	APM064GMFQN-3BTGW
128GB	APM128GMFQN-3BTG	APM128GMFQN-3BTGW

Note: Valid combinations are those products in mass production or will be in mass production. Consult your Apacer sales representative to confirm availability of valid combinations and to determine availability of new combinations.

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Revision History

Revision	Description	Date
0.1	Preliminary release	11/16/2016
0.2	Updated performance and power consumption values for 2-16GB	11/21/2016
0.3	Added 1.5 LED Indicator Behavior	11/25/2016
1.0	- Removed 2-4GB support - Updated performance values for 8GB	1/17/2017

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